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PATENT  
Attorney's Doc. No. 4591-170  
Client Ref. No. IE10189-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent No.: US 6,844,604 B2  
Inventor: Lee et al.  
Issued: January 18, 2005

For: DIELECTRIC LAYER FOR SEMICONDUCTOR DEVICE AND METHOD  
FOR MANUFACTURING THE SAME

Ser. No.: 09/776,059  
Group Art Unit: 2814

Filed: Feb. 2, 2001  
Examiner: Douglas Wille

TRANSMITTAL LETTER

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**Certificate**  
**JAN 03 2006**  
**of Correction**

Enclosed for filing are the following:

- ☒ Request for Certificate of Correction
- ☒ Certificate of Correction Form PTO 1050
- ☒ Return postcard
- ☒ Any deficiency or overpayment should be charged or credited to deposit account number 13-1703.

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.

Hosoon Lee  
Reg. No. 56,737

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Date: December 22, 2005

Kelly Andrews

JAN 05 2006



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REQUEST FOR CERTIFICATE OF CORRECTION

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Alexandria, VA 22313-1450

Upon comparison of the above-identified original Letters Patent with applicant's copy of the application therefore, the following error in the original Letters Patent has been noted:

- At column 4, line 52, please replace "of 900° C." with --of 900° C--
- At column 6, line 49, please replace "can be increased forming" with --can be lowered forming--
- At column 6, line 53, please replace "of Al<sub>2</sub>O<sub>3</sub> as illustrated" with --of Al<sub>2</sub>O<sub>3</sub> as illustrated--
- At column 6, line 60, please replace "temperature can be increased" with --temperature can be lowered--
- At column 6, line 65, please replace "800-850° C. when" with --800-850° C when--
- At column 6, line 66, please replace "can be 900° C. when" with --can be 900° C when--
- At column 7, line 6, please replace "can be increased compared" with --can be reduced compared--
- At column 7, lines 61-64, please replace "6, which shows the charge pumping current of SiO<sub>2</sub> and Al<sub>2</sub>O<sub>3</sub>. As can be seen, the interface trap density of Al<sub>2</sub>O<sub>3</sub> is greater than SiO<sub>2</sub>. Such" with --6. Such--
- At column 10, line 21, please replace "dielectric layer wherein" with --dielectric layer, wherein--

Applicant respectfully requests that a Certificate of Correction calling attention to the above error be issued pursuant to Rule 322 of the Patent Office and Title 35, United States Code, Section 254. Two copies of a Certificate of Correction form are enclosed.

JAN 05 2006



Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.

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## UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO : US 6,844,604 B2

DATED : January 18, 2005

INVENTOR(S) : Lee et al.

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MAILING ADDRESS OF SENDER:

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Portland, Oregon 97204

PATENT NO. US 6,844,604 B2

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